TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74HC21AP, TC74HC21AF, TC74HC21AFN

#### **DUAL 4-INPUT AND GATE**

The TC74HC21A is a high speed CMOS 4-INPUT AND GATE fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

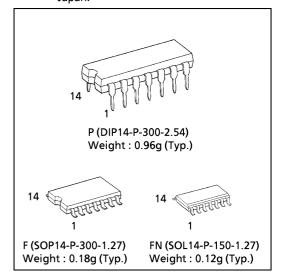
The internal circuit is composed of 4 stages including buffer a output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

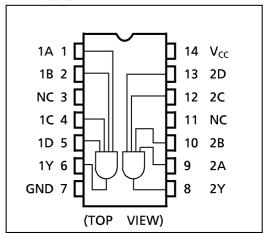
#### **FEATURES:**

- High Speed······tod = 10ns(typ.) at  $V_{CC}$  = 5V
- Low Power Dissipation ············ $I_{CC} = 1\mu A(Max.)$  at  $Ta = 25^{\circ}C$
- High Noise Immunity  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Output Drive Capability ..... 10 LSTTL Loads
- Symmetrical Output Impedance… | I<sub>OH</sub> | = I<sub>OL</sub> = 4mA(Min.)
- Balanced Propagation Delays ····· t<sub>pLH</sub> ≃ t<sub>pHL</sub>
- Wide Operating Voltage Range ···· V<sub>CC</sub> (opr.) = 2V~6V
- Pin and Function Compatible with 74LS21

## (Note) The JEDEC SOP (FN) is not available in Japan.



#### PIN ASSIGNMENT



### TRUTH TABLE

	lı		Outputs	
Α	В	С	D	Υ
L	Х	Х	Х	L
Х	L	Х	Х	L
Х	Х	L	Х	L
Х	Х	Х	L	L
Н	Н	Н	Н	Н

#### IEC LOGIC SYMBOL

1A (1) 1B (2)	&	(6)	
1C (5)		<u>(6)</u> 1Y	
2A (10) 2B (12) 2C (13)		<u>(8)</u> 2Y	

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## **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>cc</sub>	<b>−</b> 0.5 <b>~</b> 7	٧
DC Input Voltage	VIN	$-0.5 \sim V_{CC} + 0.5$	٧
DC Output Voltage	V <sub>OUT</sub>	$-0.5 \sim V_{CC} + 0.5$	<b>\</b>
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	± 20	mA
DC Output Current	I <sub>OUT</sub>	± 25	mA
DC V <sub>CC</sub> / Ground Current	I <sub>cc</sub>	± 50	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

\*500mW in the range of Ta=  $-40^{\circ}\text{C}\sim65^{\circ}\text{C}$ . From Ta=65°C to 85°C a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

### **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V <sub>cc</sub>	2~6	V
Input Voltage	V <sub>IN</sub>	0~V <sub>cc</sub>	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>cc</sub>	V
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	$0 \sim 1000 (V_{CC} = 2.0V)$ $0 \sim 500 (V_{CC} = 4.5V)$ $0 \sim 400 (V_{CC} = 6.0V)$	ns

### DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V <sub>cc</sub>	7	a = 25°0	C	Ta = -4	.0~85°C	UNIT
PARAIVIETER	STIVIBUL			(V)	MIN.	TYP.	MAX.	MIN.	MAX.	ONIT
High - Level Input Voltage	VIH				1.50 3.15 4.20		_ _ _	1.50 3.15 4.20	_ _ _	V
Low - Level Input Voltage	VIL			2.0 4.5 6.0		  -  -	0.50 1.35 1.80	_ _ _	0.50 1.35 1.80	V
High - Level Output Voltage	V <sub>OH</sub>	$V_{OH}$ $V_{IN} = V_{IH}$	$I_{OH} = -20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0		1.9 4.4 5.9		V
				$I_{OH} = -4 \text{ mA}$ $I_{OH} = -5.2 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	_	4.13 5.63	_
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>OL</sub> V <sub>IN</sub> =	Ι <sub>ΟL</sub> = 20μΑ	2.0 4.5 6.0		0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	V
	Vol V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 4  mA$ $I_{OL} = 5.2  mA$	4.5 6.0	1 1	0.17 0.18	0.26 0.26	-	0.33 0.33		
Input Leakage Current	I <sub>I N</sub>	$V_{IN} = V_{C}$	<sub>C</sub> or GND	6.0	ı	ı	±0.1	_	± 1.0	
Quiescent Supply Current	I <sub>CC</sub>	$V_{IN} = V_{C}$	<sub>C</sub> or GND	6.0	-	_	1.0	_	10.0	<b>μΑ</b>

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## AC ELECTRICAL CHARACTERISTICS ( $C_L = 15pF$ , $V_{CC} = 5V$ , $Ta = 25^{\circ}C$ , Input $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>		_	4	8	ns
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>		_	10	17	

## AC ELECTRICAL CHARACTERISTICS ( $C_L = 50pF$ , Input $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	MBOL TEST CONDITION IS		Ta = 25°0			$Ta = -40 \sim 8!$		LINIT
FARAIVIETER	STIVIBUL	TEST CONDITION	$V_{CC}(V)$	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
	t <sub>TLH</sub>		2.0	_	30	75	_	95	
Output Transition Time			4.5	_	8	15	l —	19	
	t <sub>THL</sub>		6.0	_	7	13	_	16	ns
	<b>+</b>		2.0	-	40	100	_	125	
Propagation Delay Time	t <sub>pLH</sub>		4.5	_	13	20	-	25	
	t <sub>pHL</sub>		6.0	1	11	17	_	21	
Input Capacitance	C <sub>IN</sub>				5	10	_	10	nE
Power Dissipation Capacitance	C <sub>PD</sub> (1)			_	25	_	_	_	pF

Note (1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

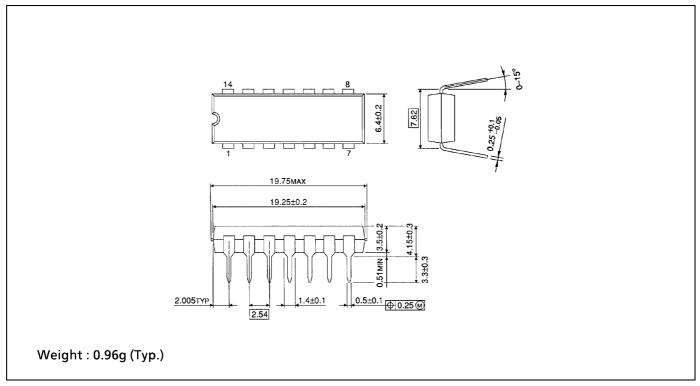
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Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2$  (per Gate)

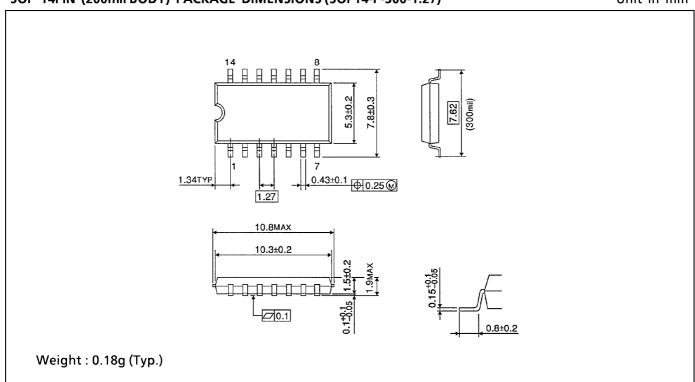
## **DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)**

Unit in mm



## SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

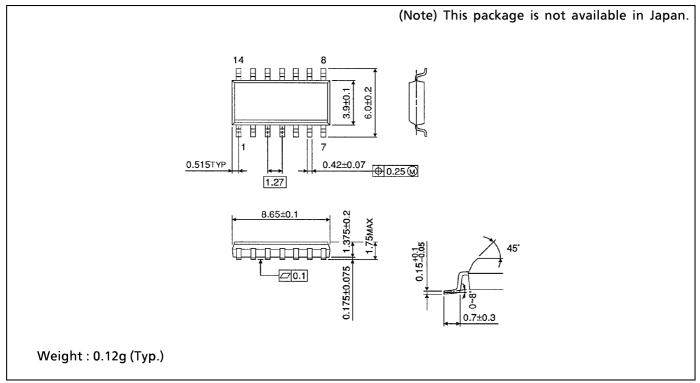
Unit in mm



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## SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150 -1.27)

Unit in mm



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